

#### **DESCRIPTION**

The LM13700MX/NOPB-CN series consists of two current-controlled transconductance amplifiers, each with differential inputs and a push-pull output. The two amplifiers share common supplies but otherwise operate independently. Linearizing diodes are provided at the inputs to reduce distortion and allow higher input levels. The result is a 10-dB signal-to-noise improvement referenced to 0.5 percent THD. High impedance buffers are provided which are especially designed to complement the dynamic range of the amplifiers. The output buffers of the LM13700M differ from those of the LM13700MX/NOPB-CN in that their input bias currents (andthus their output DC levels) are independent of labc. This may result in performance superior tothat of the LM13700MX/NOPB-CN in audio applications.

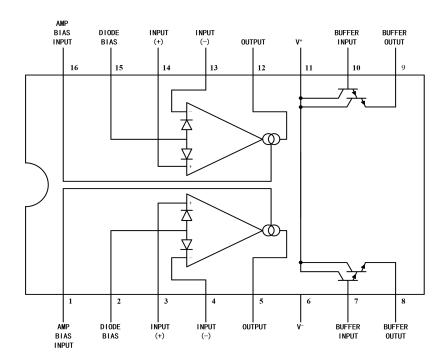
#### **FEATURES**

- gm Adjustable Over 6 Decades
- Excellent gm Linearity
- Excellent Matching Between Amplifiers
- Linearizing Diodes for reduced output distortion
- High Impedance Buffers
- High Output Signal-to-Noise Ratio

## **APPLICATIONS**

- Current-Controlled Amplifiers
- Stereo Audio Amplifiers
- Current-Controlled Impedances
- Current-Controlled Filters
- Current-Controlled Oscillators
- Multiplexers
- Sample-and-Hold Circuits

## **Pin Configuration**



# **Dual Operational Transconductance Amplifiers With Linearizing Diodes and Buffers**

## **Absolute Maximum Ratings**

Over operating free-air temperature range (unless otherwise noted) (1)

PARAMETER	MIN	MAX	UNIT	
Consol Mallage Ma (Mr.) (Mr.)	Single-supply		+36	V
Supply Voltage, Vs=(V+) - (V-)	Dual-supply	-18	+18	V
DC Input Voltage		-V <sub>S</sub>	+V <sub>S</sub>	V
Differential input voltage		-5	+5	V
Diode bias current (I <sub>D</sub> )			2	mA
Amplifier bias current (I <sub>ABC</sub> )			2	mA
Buffer output current(I <sub>Buffer</sub> ) <sup>(2)</sup>			20	mA
Output short circuit duration		Conti		
Storage temperature(Ts)		-65	+150	°C

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

Note 2: Buffer output current should be limited so as to not exceed package dissipation.

## **Recommended Operating Conditions**

Over operating free-air temperature range (unless otherwise noted)

PARAMETER	MIN	ТҮР	MAX	UNIT
V <sub>s</sub> (single-supply configuration)	10		32	V
V+ (dual-supply configuration)	5		16	V
V- (dual-supply configuration)	-16		-5	V
Operating Temperature Range(T <sub>A</sub> )	-20		85	°C

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# **Dual Operational Transconductance Amplifiers With Linearizing Diodes and Buffers**

### **ELECTRICAL CHARACTERISTICS**

(These specifications apply for  $V_S=\pm15V$ ,  $T_A=25^{\circ}C$ ,  $I_{ABC}=500\mu A$ , pins 2 and 15 open unless otherwise specified. The inputs to the buffers are grounded and outputs are open.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
land offert college	Vos	Over specified temperature range		0.4	4	mV
Input offset voltage		I <sub>ABC</sub> =5uA		0.3	4	mV
Vos including diodes	V <sub>OS_D</sub>	Diode bias current (I₀)=500μA		0.5	5	mV
Input offset change	$\Delta V_{OS}$	5uA≤I <sub>ABC</sub> ≤500uA		0.1	3	mV
Input offset current	los			0.1	0.6	uA
Leavel Istana a consta				0.4	5	uA
Input bias current	Ι <sub>Β</sub>	Over specified temperature range		1	8	uA
Face and the control of the control	gm	Take 10mV and 25mV to calculate	6700	9600	13000	μS
Forward transconductance		Over specified temperature range	5400			μS
gm tracking	gm_t			0.3		dB
	lpk	R <sub>L</sub> =0, I <sub>ABC</sub> =5uA		5		uA
Peak output current		R <sub>L</sub> =0, I <sub>ABC</sub> =500uA	350	500	650	uA
		R <sub>L</sub> =0, Over specified temperature range	300			uA
Supply current	I <sub>CC</sub>	I <sub>ABC</sub> =500uA, both channels		2.2		mA
Common-mode range	Vic		±12	±13.5		V
Common-mode rejection ratio	CMRR		80	110		dB
Crosstalk	Crosstalk	Referred to input <sup>(1)</sup> , 20Hz <f<20khz< td=""><td></td><td>100</td><td></td><td>dB</td></f<20khz<>		100		dB
Differential input current	Id	I <sub>ABC</sub> =0, input=±4V		0.02	100	nA
Leakage current	I <sub>LEAK</sub>	I <sub>ABC</sub> =0(refer to test circuit)		0.2	100	nA
Input resistance	Z <sub>IN</sub>		10	26		kΩ
Open-loop bandwidth	BW			2		MHz
Slew rate	SR	Unity gain compensated		50		V/µs
Buffer input current	I <sub>BIN</sub>	See (1)		0.5	2	uA
Peak buffer output voltage	Ipkout-buf	See (1)	10			V
PEAK OUTPUT VOLTAGE						
Positive	V <sub>OP</sub>	R <sub>L</sub> =∞, 5uA≤I <sub>ABC</sub> ≤500uA	12	14.2		V
Negative	V <sub>ON</sub>	R <sub>L</sub> =∞, 5uA≤I <sub>ABC</sub> ≤500uA	-12	-14.4		V
V <sub>OS</sub> SENSITIVITY						
Positive		ΔVos/ΔV+		20	150	μV/V

<sup>(1)</sup> These specifications apply for  $V_S=\pm15V$ ,  $I_{ABC}=500\mu A$ ,  $R_{OUT}=5k\Omega$  connected from the buffer output to  $-V_S$  and the input of the buffer is connected to the transconductance amplifier output.

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# **Dual Operational Transconductance Amplifiers With Linearizing Diodes and Buffers**

## **TYPICAL CHARACTERISTICS**

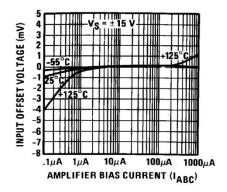


Figure 1. Input Offset Voltage vs IABC

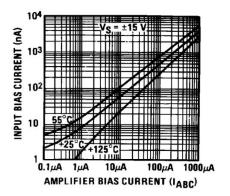


Figure 3. Input BIAS Current vs IABC

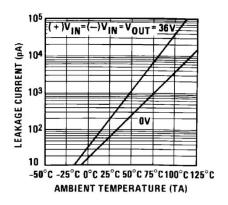


Figure 5. Leak Current vs Temperature

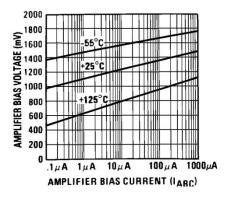


Figure 7. Amplifier Bias Voltage vs IABC

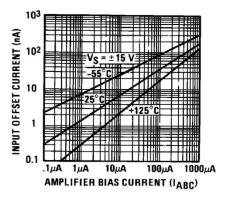


Figure 2. Input Offset Current vs IABC

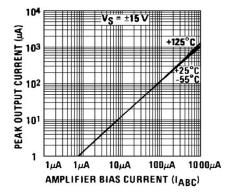


Figure 4. Peak Output Current vs IABC

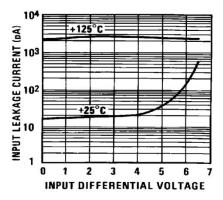


Figure 6. Input Leak Current vs Input Different Voltage

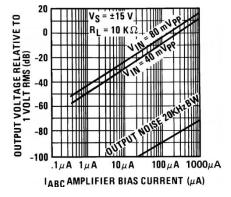


Figure 8. Output Voltage vs IABC

## **Detailed Description**

#### Overview

The LM13700MX/NOPB-CN is a two channel current controlled differential input transconductance amplifier with additional output buffers. The inputs include linearizing diodes to reduce distortion, and the output current is controlled by a dedicated pin.

The outputs can sustain a continuous short to ground.

#### **Functional Block Diagram**

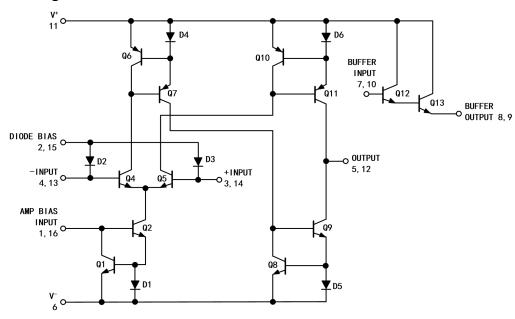


Figure 9. One Operational Transconductance Amplifier

#### (1) Feature Description

The differential transistor pair  $Q_4$  and  $Q_5$  form a transconductance stage in that the ratio of their collector currents is defined by the differential input voltage according to the transfer function:

$$V_{IN} = \frac{kT}{q} \ln \frac{I_5}{I_a} \tag{1}$$

where  $V_{IN}$  is the differential input voltage, kT/q is approximately 26 mV at 25  $^{\circ}$ C and I<sub>5</sub> and I<sub>4</sub> are the collector currents of transistors Q<sub>5</sub> and Q<sub>4</sub> respectively. With the exception of Q<sub>12</sub> and Q<sub>13</sub>, all transistors and diodes are identical in size. Transistors Q<sub>1</sub> and Q<sub>2</sub> with Diode D1 form a current mirror which forces the sum of currents I<sub>4</sub> and I<sub>5</sub> to equal I<sub>ABC</sub>:

$$I_4 + I_5 = I_{ABC} \tag{2}$$

where I<sub>ABC</sub> is the amplifier bias current applied to the gain pin.

For small differential input voltages the ratio of  $I_4$  and  $I_5$  approaches unity and the Taylor series of the In function is approximated as:

$$\frac{kT}{q}\ln\frac{I_5}{I_4} = \frac{kT}{q} \frac{I_5 - I_4}{I_4}$$

$$I_4 \approx I_5 \approx \frac{I_{ABC}}{2} \tag{3}$$

$$V_{IN} \left[ \frac{I_{ABC}^{q}}{2kT} \right] = I_5 - I_4 \tag{4}$$



# **Dual Operational Transconductance Amplifiers**With Linearizing Diodes and Buffers

Collector currents  $I_4$  and  $I_5$  are not very useful by themselves and it is necessary to subtract one current from the other. The remaining transistors and diodes form three current mirrors that produce an output current equal to  $I_5$  minus  $I_4$  thus:

$$V_{IN} \left[ \frac{I_{ABC}^{q}}{2kT} \right] = I_{OUT} \tag{5}$$

The term in brackets is then the transconductance of the amplifier and is proportional to IABC.

#### (2) Linearizing Diodes

For differential voltages greater than a few millivolts, Equation 3 becomes less valid and the transconductance becomes increasingly nonlinear. Figure 10 demonstrates how the internal diodes can linearize the transfer function of the amplifier. For convenience assume the diodes are biased with current sources and the input signal is in the form of current  $I_S$ . Since the sum of  $I_A$  and  $I_S$  is  $I_{ABC}$  and the difference is  $I_{OUT}$ , currents  $I_A$  and  $I_S$  is written as follows:

$$I_4 = \frac{I_{ABC}}{2} - \frac{I_{OUT}}{2}$$
,  $I_5 = \frac{I_{ABC}}{2} + \frac{I_{OUT}}{2}$  (6)

Since the diodes and the input transistors have identical geometries and are subject to similar voltages and temperatures, the following is true:

$$\frac{kT}{q} \ln \frac{\frac{I_D}{2} + I_S}{\frac{I_D}{2} - I_S} = \frac{kT}{q} \ln \frac{\frac{I_{ABC}}{2} - \frac{I_{OUT}}{2}}{\frac{I_{ABC}}{2} - \frac{I_{OUT}}{2}}$$

$$\therefore I_{OUT} = I_S(\frac{2I_{ABC}}{I_D}) \text{ for } |I_S| < \frac{I_D}{2}$$
(7)

Notice that in deriving Equation 7 no approximations have been made and there are no temperature-dependent terms. The limitations are that the signal current not exceed  $I_D/2$  and that the diodes be biased with currents. In practice, replacing the current sources with resistors will generate insignificant errors.

## (3) Device Functional Modes

Use in single ended or dual supply systems requires minimal changes. The outputs can support a sustained short to ground. Note that use of the LM13700MX/NOPB-CN in 5 V supply systems requires will reduce signal dynamic range.

this is due to the PNP transistors having a higher VBE than the NPN transistors.

## (4) Output Buffers

Each channel includes a separate output buffer which consists of a Darlington pair transistor that can drive up to 20mA.

## **Application and Implementation**

#### **Application Information**

An OTA is a versatile building block analog component that can be considered an ideal transistor. The LM13700MX/NOPB-CN can be used in a wide variety of applications, from voltage controlled amplifiers and filters to VCOs. The 2 well matched, independent channels make the LM13700MX/NOPB-CN well suited for stereo audio applications.

## **Typical Application**

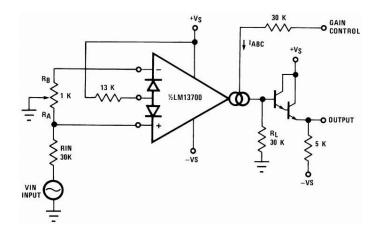


Figure 10 . Voltage Controlled Amplifier

#### (1) Design Requirements

For this example application, the system requirements provide a volume control for a 1  $V_P$  input signal with a THD<0.1% using ±15V supplies. The volume control varies between -13 V and 15 V and needs to provide an adjustable gain range of >30dB.

## (2) Detailed Design Procedure

Using the linearizing diodes is recommended for most applications, as they greatly reduce the output distortion. It is required that the diode bias current,  $I_D$  be greater than twice the input current,  $I_S$ . As the input voltage has a DC level of 0V, the Diode Bias input pins are 1 diode drop above 0V, which is +0.7V. Tying the bias to the clean V+ supply, results in a voltage drop of 14.3V across  $R_D$ . Using the recommended 1mA for  $I_D$  is appropriate here, and with  $V_S$ =+15 V, the voltage drop is 14.3V, and so using the standard value of  $13k\Omega$  is acceptable and will provide the desired gain control.

To obtain the <0.1% THD requirement, the differential input voltage must be <60mV<sub>PP</sub> when the linearizing diodes are used. The input divider on the input will reduce the  $1V_P$  input to  $33mV_{PP}$ , which is within the desired spec.

Next, set  $I_{BIAS}$ . The Bias Input pins (pins 1 or 16), are 2 diode drops above the negative supply, and therefore  $V_{BIAS}$ =2( $V_{BE}$ )+V-, which for this application is -13.6V. To set  $I_{BIAS}$  to 1mA when  $V_{C}$ =15V requires a 28.6k $\Omega$ ; 30k $\Omega$  is a standard value and is used for this application. The gain will be linear with the applied voltage.

## (3) Application Curve

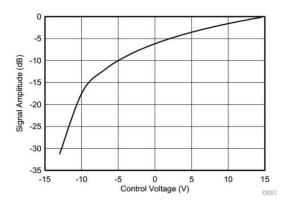


Figure 11 . Signal Amplitude vs Control Voltage

#### **System Examples - Voltage-Controlled Amplifiers**

Figure 13 shows how the linearizing diodes is used in a voltage-controlled amplifier. To understand the input biasing, it is best to consider the  $13k\Omega$  resistor as a current source and use a Thevenin equivalent circuit as shown in Figure 14. This circuit is similar to Figure 12 and operates the same. The potentiometer in Figure 14 is adjusted to minimize the effects of the control signal at the output.

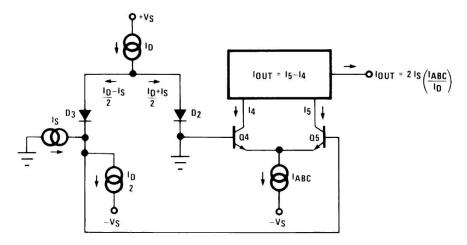


Figure 12 . Linearizing Diodes

For optimum signal-to-noise performance, I<sub>ABC</sub> should be as large as possible as shown by the Output Voltage vs Amplifier Bias Current graph. Larger amplitudes of input signal also improve the S/N ratio. The linearizing diodes help here by allowing larger input signals for the same output distortion as shown by the Distortion vs. Differential Input Voltage graph. S/N may be optimized by adjusting the magnitude of the input signal via R<sub>IN</sub>(Figure 13) until the output distortion is below the desired level. The output voltage swing can then be set at any level by selecting R<sub>L</sub>.

Although the noise contribution of the linearizing diodes is negligible relative to the contribution of the amplifier's internal transistors,  $I_D$  should be as large as possible. This minimizes the dynamic junction resistance of the diodes ( $r_e$ ) and maximizes their linearizing action when balanced against  $R_{IN}$ . A value of 1mA is recommended for  $I_D$  unless the specific application demands otherwise.

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# **Dual Operational Transconductance Amplifiers With Linearizing Diodes and Buffers**

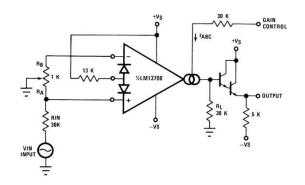


Figure 13. Voltage-Controlled Amplifier

# | OUT = IS (21ABC) | OUT = IS (2

Figure 14. Equivalent VCA Input Circuit

## **Other Applications**

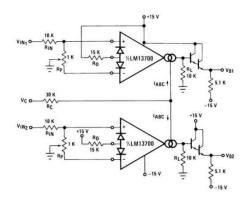


Figure 15. Stereo Volume Control

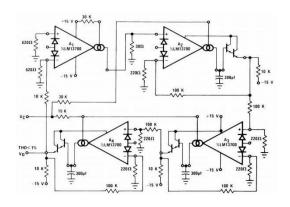


Figure 16. Sinusoidal VCO

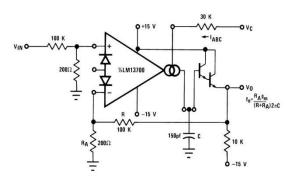


Figure 17. Voltage-Controlled Low-Pass Filter

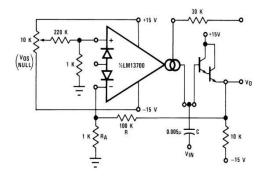


Figure 18. Voltage-Controlled Hi-Pass Filter

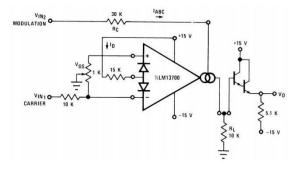


Figure 19. Amplitude Modulator

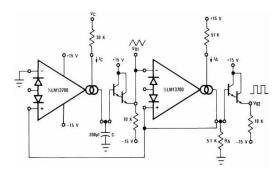


Figure 20. Triangular/Square-Wave VCO

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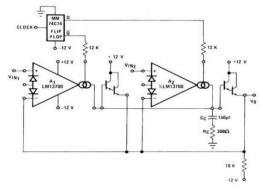


Figure 21. Multiplexer

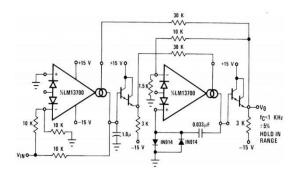


Figure 22. Phase Lock Loop

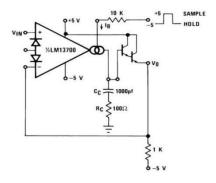


Figure 23. Sample-Hold Circuit

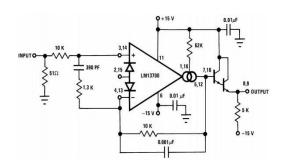


Figure 24. Unity Gain Follower

#### **Test Circuits**

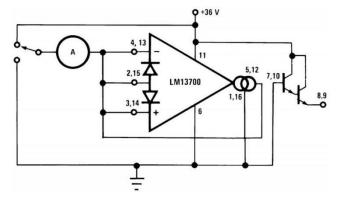


Figure 25. Leakage Current Test Circuit

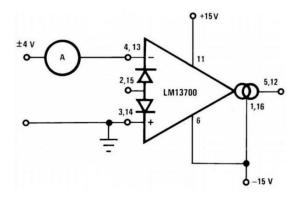
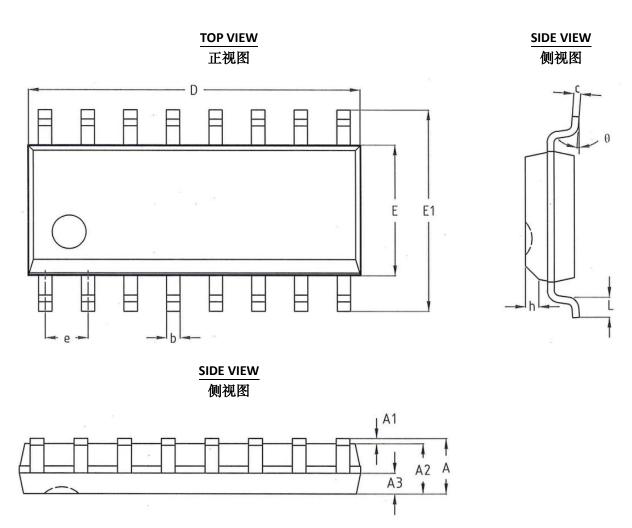


Figure 26. Differential Input Current Test Circuit

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# **Dual Operational Transconductance Amplifiers With Linearizing Diodes and Buffers**

## PACKAGE OUTLINE DIMENSIONS SOP16



SYMBOL	MILLIMETER			0,440.01	MILLIMETER		
	MIN	NOM	MAX	SYMBOL	MIN	NOM	MAX
Α	-	-	1.75	E	3.80	3.90	4.00
A1	0.10	-	0.25	E1	5.80	6.00	6.20
A2	1.35	1.45	1.55	е		1.27 BSC	
А3	0.60	0.65	0.70	h	0.30	-	0.50
b	0.35	1	0.50	L	0.40	-	0.80
С	0.19	1	0.25	θ	0°	-	8°
D	9.80	9.90	10.00				



# **Dual Operational Transconductance Amplifiers With Linearizing Diodes and Buffers**

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